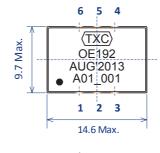
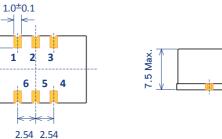
· For base station and wireless communication application.

14x9 mm Typ.  20MHz  CMOS  15pF, Typ.  3.3V  3.0 W Max. While Warm-Up 1.25 W Max. at Steady State  5 Minutes Typ.  ± 0.2 ppm Max.  - 40 to + 85 °C  ± 30 to ± 50 ppb Max.
CMOS  15pF, Typ.  3.3V  3.0 W Max. While Warm-Up 1.25 W Max. at Steady State  5 Minutes Typ.  ± 0.2 ppm Max.  - 40 to + 85 °C
15pF, Typ. 3.3V 3.0 W Max. While Warm-Up 1.25 W Max. at Steady State 5 Minutes Typ. ± 0.2 ppm Max 40 to + 85 °C
3.3V 3.0 W Max. While Warm-Up 1.25 W Max. at Steady State 5 Minutes Typ. ± 0.2 ppm Max 40 to + 85 °C
3.0 W Max. While Warm-Up 1.25 W Max. at Steady State  5 Minutes Typ.  ± 0.2 ppm Max.  - 40 to + 85 °C
1.25 W Max. at Steady State 5 Minutes Typ. ± 0.2 ppm Max 40 to + 85 °C
± 0.2 ppm Max. - 40 to + 85 °C
- 40 to + 85 °C
± 30 to ± 50 ppb Max.
10 ppb Max. for $\pm$ 5 % Variation
10 ppb Max. for ± 5 % Variation
<± 200 ppb / year
0 to 3.3 V
± 1.0 ppm Typ.
10% Max.
NA

- [#1] Contact sales agent for other frequency requirement
  [#2] Available output type: CMOS for all series, Sinewave for OB & OC series
  [#3] Contact sales agent for other temperature range and stability requirement
- [#4] Contact sales agent for other Vc range requirement

## **Dimensions**





Pin function:

Pad 1: Vc Pad 2: N.C

Pad 3: GND Pad 4: Output

Pad 5: N.C.

Pad 6: Vcc

Units: mm

Remark : Specification subject to change without prior notice. Please confirm with our sales. http://www.txccorp.com